

# **Isc N-Channel MOSFET Transistor**

# IPA65R310CFD

#### FEATURES

- With TO-220F package
- · Low input capacitance and gate charge
- · Low gate input resistance
- Reduced switching and conduction losses
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATIONS

Switching applications

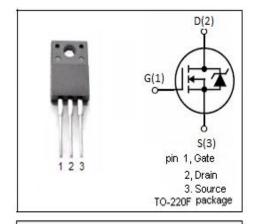


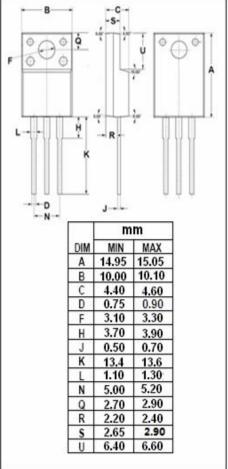
### ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
$V_{DSS}$	Drain-Source Voltage	650	V
V <sub>GSS</sub>	Gate-Source Voltage	±20	V
I <sub>D</sub>	Drain Current-Continuous @Tc=25℃ (V <sub>GS</sub> at 10V) Tc=100℃	11.4 7.2	Α
I <sub>DM</sub>	Drain Current-Single Pulsed	34.4	Α
P <sub>D</sub>	Total Dissipation @Tc=25℃	32	W
Tj	Max. Operating Junction Temperature	-55~150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
Rth(ch-c)	Channel-to-case thermal resistance	3.9	°C/W	
Rth(ch-a)	Channel-to-ambient thermal resistance	80	°C/W	







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### • ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =1mA	650			V
$V_{\text{GS(th)}}$	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; I <sub>D</sub> =0.4mA	3.5	4	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =4.4A		0.28	0.31	Ω
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0V			±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = 650V; V <sub>GS</sub> = 0V;Tj=25°C V <sub>DS</sub> =650V; V <sub>GS</sub> = 0V; Tj=150°C		150	1	μА
V <sub>SDF</sub>	Diode forward voltage	I <sub>SD</sub> =6.6A, V <sub>GS</sub> = 0 V		0.9		V

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